

# **isc** Silicon NPN Power Transistor

# **BU209A**

#### **DESCRIPTION**

- High Voltage Capability
- · High Peak Power
- High Current Capability
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

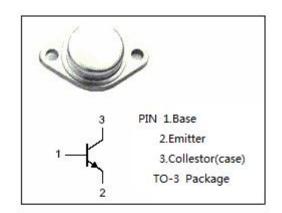
 Designed for use in horizontal deflection circuits in color TV receivers.

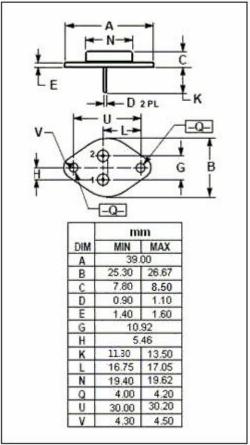
### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CES</sub>	Collector-Emitter Voltage	1500	V
VCEO	Collector-Emitter Voltage	800	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	4	А
I <sub>CM</sub>	Collector Current-Peak	7.5	А
I <sub>B</sub>	Base Current-Continuous	2.5	А
Івм	Base Current-Peak	4	А
Pc	Collector Power Dissipation @Tc≤95°C	12.5	W
TJ	Junction Temperature 150		$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature	-65~150	$^{\circ}$

# THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	1.6	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA	1500			V			
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 10mA ; I <sub>C</sub> = 0	5			V			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 1.3A			5.0	V			
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	Ic= 3A; I <sub>B</sub> = 1.3A			1.5	V			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 5V	2.25						
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V;f <sub>test</sub> = 1MHz		125		pF			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A;V <sub>CE</sub> = 5V;f <sub>test</sub> = 5MHz		7		MHz			
Switching Times									
ts	Storage Time	- I <sub>C</sub> = 3A; I <sub>B</sub> = 1.8A;L <sub>B</sub> = 10 μ H			10	μS			
t <sub>f</sub>	Fall Time				0.7	μs			

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